

K-BAND SUPER LOW NOISE AMPLIFIER
N-CHANNEL GaAs HJ-FET

FEATURES

- Super low noise figure, high associated gain
NF = 0.7 dB TYP., G_a = 13.5 dB TYP. @ f = 20 GHz
- K-band Micro-X plastic (S03) package

APPLICATIONS

- 20 GHz band DBS LNB
- Other K-band communication systems

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE3517S03-T1C	NE3517S03-T1C-A	S03 (Pb-Free)	2 kpcs/reel	E	<ul style="list-style-type: none">• 8 mm wide embossed taping• Pin 4 (Gate) faces the perforation side of the tape
NE3517S03-T1D	NE3517S03-T1D-A		10 kpcs/reel		

Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: NE3517S03-A

ABSOLUTE MAXIMUM RATINGS ($T_A = +25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	V_{DS}	4	V
Gate to Source Voltage	V_{GS}	-3	V
Drain Current	I_D	I_{DSS}	mA
Gate Current	I_G	100	μA
Total Power Dissipation	P_{tot} <small>Note</small>	165	mW
Channel Temperature	T_{ch}	+125	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +125	$^\circ\text{C}$

Note Mounted on $1.08 \text{ cm}^2 \times 1.0 \text{ mm}$ (t) glass epoxy PCB

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

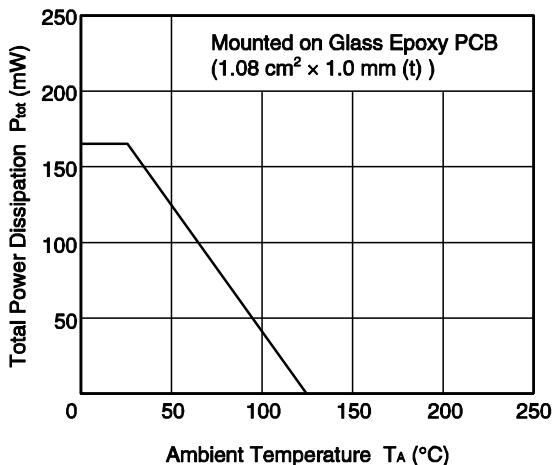
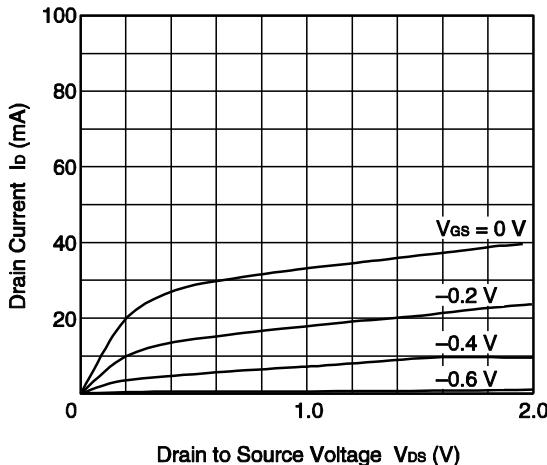
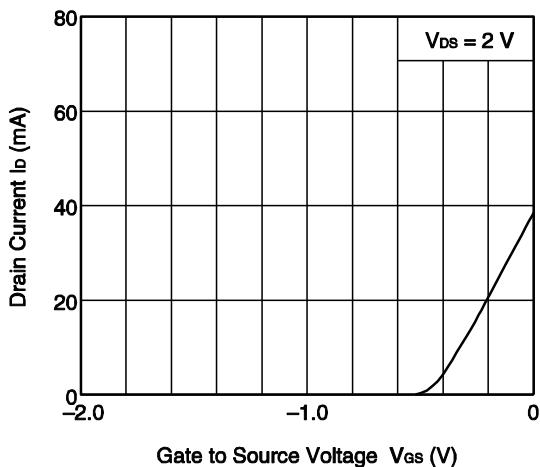
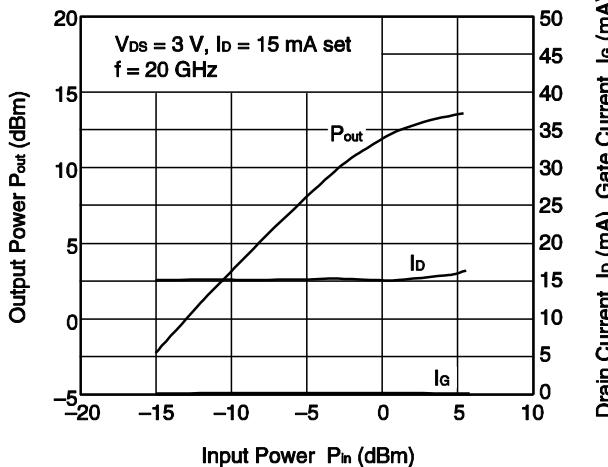
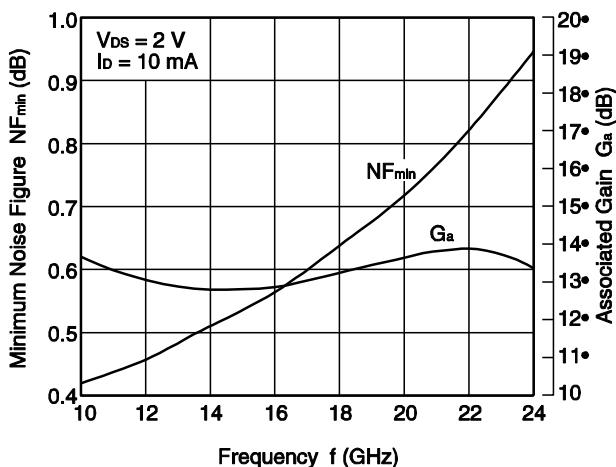
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RECOMMENDED OPERATING CONDITIONS ($T_A = +25^\circ\text{C}$)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	V_{DS}	1	2	3	V
Drain Current	I_D	5	10	15	mA
Input Power	P_{in}	–	–	0	dBm

ELECTRICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	I_{GSO}	$V_{GS} = -3\text{ V}$	–	0.5	10	μA
Saturated Drain Current	I_{DS}	$V_{DS} = 2\text{ V}, V_{GS} = 0\text{ V}$	25	40	70	mA
Gate to Source Cutoff Voltage	$V_{GS(\text{off})}$	$V_{DS} = 2\text{ V}, I_D = 100\text{ }\mu\text{A}$	–0.2	–0.7	–1.5	V
Transconductance	g_m	$V_{DS} = 2\text{ V}, I_D = 10\text{ mA}$	40	55	–	mS
Noise Figure	NF	$V_{DS} = 2\text{ V}, I_D = 10\text{ mA}, f = 20\text{ GHz}$	–	0.7	1.0	dB
Associated Gain	G_a		11.0	13.5	–	dB

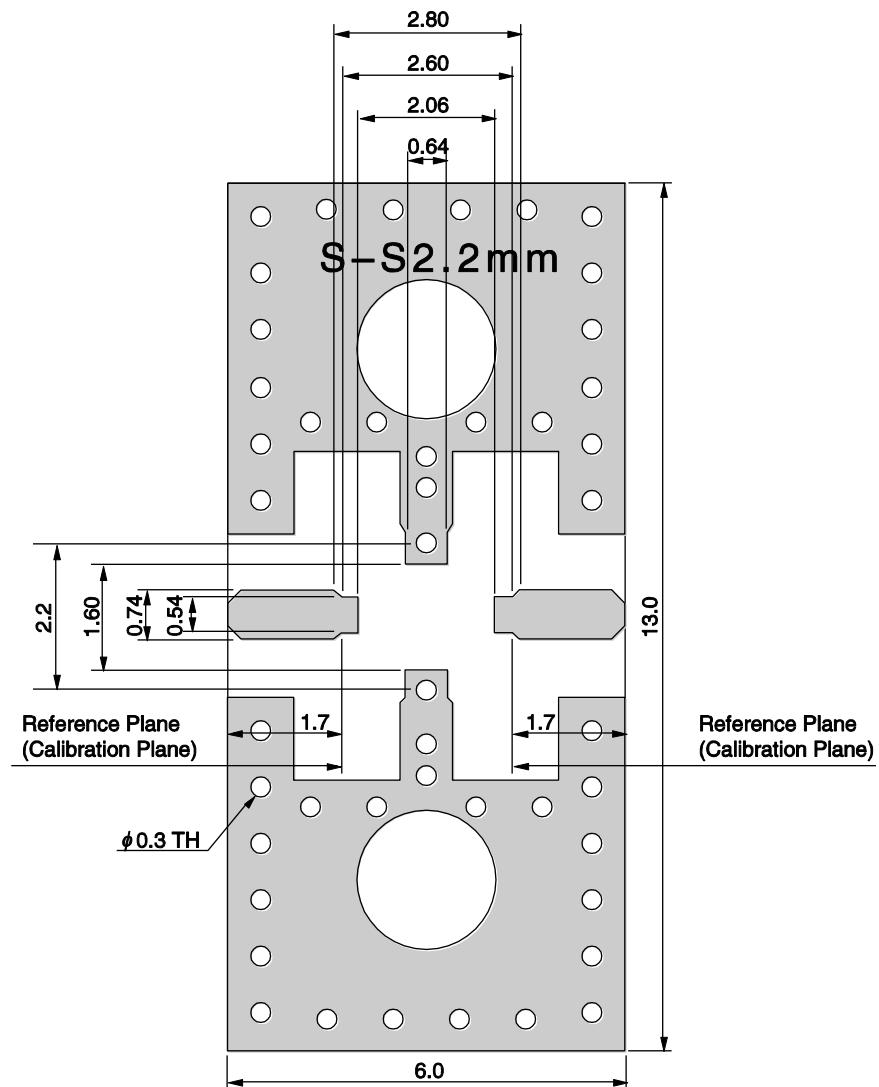
TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise specified)TOTAL POWER DISSIPATION
vs. AMBIENT TEMPERATUREDRAIN CURRENT
vs. DRAIN TO SOURCE VOLTAGEDRAIN CURRENT
vs. GATE TO SOURCE VOLTAGEOUTPUT POWER, DRAIN CURRENT,
GATE CURRENT vs. INPUT POWERMINIMUM NOISE FIGURE,
ASSOCIATED GAIN vs. FREQUENCY

Remark The graphs indicate nominal characteristics.

S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- [Click here to download S-parameters.](#)
- [RF and Microwave] ® [Device Parameters]
- URL <http://www.necel.com/microwave/en/>

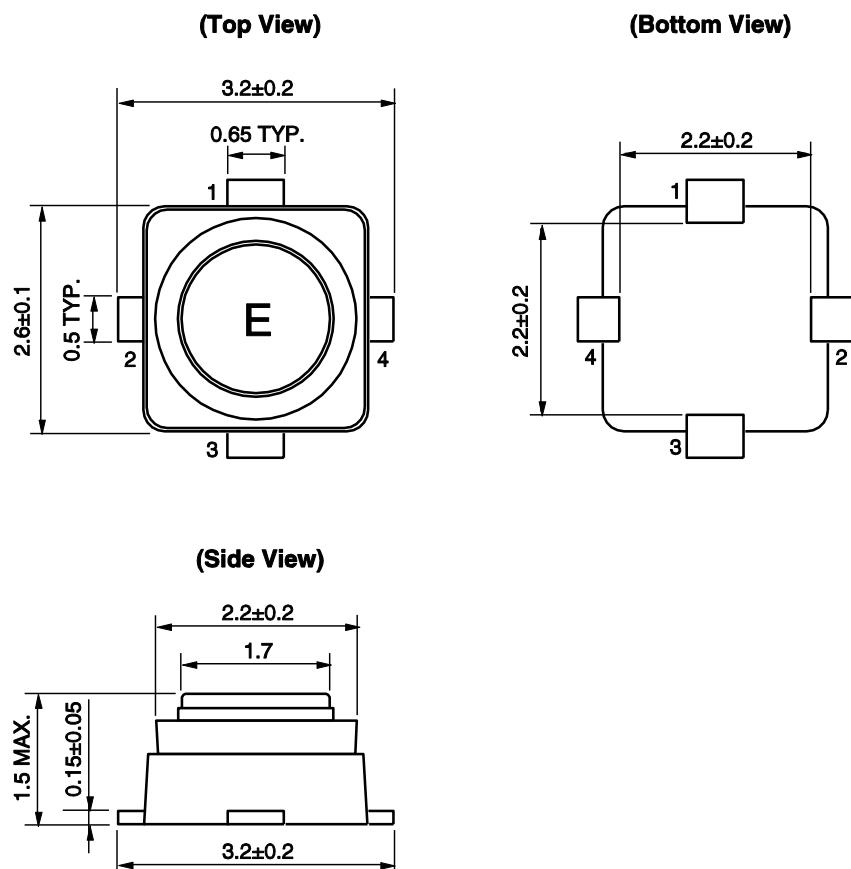
RF MEASURING LAYOUT PATTERN (REFERENCE ONLY) (UNIT: mm)



RT/duroid 5880/ROGERS
 $t = 0.254$ mm
 $\epsilon_r = 2.20$
 $\tan \delta = 0.0009$ @ 10 GHz
Au-flash plate

PACKAGE DIMENSIONS

S03 (UNIT: mm)



PIN CONNECTIONS

1. Source
2. Drain
3. Source
4. Gate

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
Partial Heating	Peak temperature (terminal temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

Caution**GaAs Products**

This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
- 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.